²¹⁷U α decay 2000Ma65,2005Le42

		History	
Туре	Author	Citation	Literature Cutoff Date
Full Evaluation	M. S. Basunia	NDS 181, 475 (2022)	1-Jan-2022

Parent: ²¹⁷U: E=0; $T_{1/2}$ =16 ms +21-6; $Q(\alpha)$ =8430 80; % α decay=100.0

²¹⁷U-T_{1/2}: From 2018Ko01 (A=217 evaluation).

²¹⁷U-J^{π}: In 2005Le42, J^{π} =(1/2⁻) was proposed.

²¹⁷U-Q(α): From systematics in 2021Wa16.

2000Ma65: ²¹⁷U was produced through ¹⁸²W(⁴⁰Ar,5n)²¹⁷U; Target 92% enriched; E=193 MeV; multi-strip silicon detector; $E\alpha$, $T_{1/2}$ measured.

2005Le42: ²¹⁷U was produced through ¹⁸²W(⁴⁰Ar,5n)²¹⁷U; E=186 MeV, double-sided silicon detector; $E\alpha$, $T_{1/2}$ measured.

²¹³Th Levels

$$\frac{\text{E(level)}}{0} \quad \frac{\text{J}^{\pi^{\dagger}}}{\text{5/2}^{-}} \quad \frac{\text{T}_{1/2}^{\dagger}}{146 \text{ ms} + 22 - 19}$$

[†] From Adopted Levels.

α radiations

Εα	E(level)	$I\alpha^{\ddagger}$	HF^{\dagger}	Comments	
8018 14	0	100	<6	Eα: Weighted average of 8005 20 (2000Ma65), 8024 14 (2005Le42). Uncertainty is the lower input value.	

[†] Using $r_0(^{213}\text{Th})=1.499\ 24$ is deduced from interpolation (or unweighted average) of $r_0(^{214}\text{Th})=1.512\ 14$ and $r_0(^{212}\text{Th})=1.486\ 33\ (2020\text{Si16})$.

[‡] Absolute intensity per 100 decays.